

HIGH VOLTAGE MEDIUM CURRENT DRIVER ARRAYS

DESCRIPTION

The SG2800 series integrates eight NPN Darlington pairs with internal suppression diodes to drive lamps, relays, and solenoids in many military, aerospace, and industrial applications that require severe environments. All units feature open collector outputs with greater than 50V breakdown voltages combined with 500mA current carrying capabilities. Five different input configurations provide optimized designs for interfacing with DTL, TTL, PMOS, or CMOS drive signals. These devices are designed to operate from -55°C to 125°C ambient temperature in a 18-pin dual in-line ceramic (J) package and 20-pin leadless chip carrier (LCC).

FEATURES

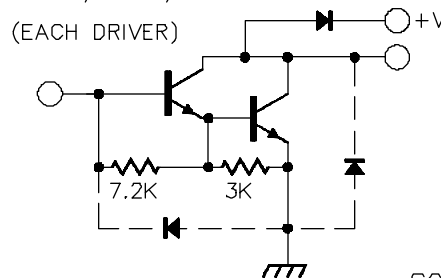
- Eight NPN Darlington pairs
- Collector currents to 600mA
- Output voltages from 50V to 95V
- Internal clamping diodes for inductive loads
- DTL, TTL, PMOS, or CMOS compatible inputs
- Hermetic ceramic package

HIGH RELIABILITY FEATURES

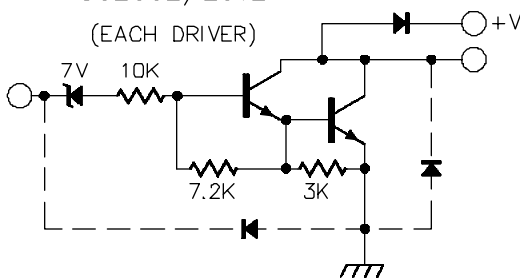
- ◆ Available to MIL-STD-883 and DESC SMD
- ◆ MIL-M38510/14106BVA - JAN2801J
- ◆ MIL-M38510/14107BVA - JAN2802J
- ◆ MIL-M38510/14108BVA - JAN2803J
- ◆ MIL-M38510/14109BVA - JAN2804J
- ◆ Radiation data available
- ◆ LMI level "S" processing available

PARTIAL SCHEMATICS

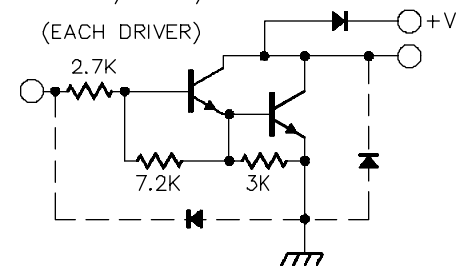
SG2801/2811/2821



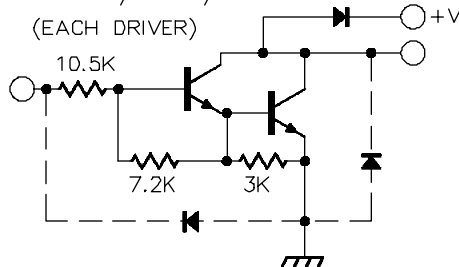
SG2802/2812



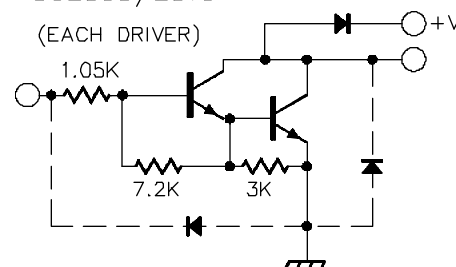
SG2803/2813/2823



SG2804/2814/2824



SG2805/2815



ABSOLUTE MAXIMUM RATINGS (Note 1)

Output Voltage, V_{CE} (SG2800, 2810 series)	50V
(SG2820 series)	95V
Input Voltage, V_{IN} (SG2802,3,4 series)	30V
Continuous Input Current, I_{IN}	25mA

Note 1. Values beyond which damage may occur.

THERMAL DATA

J Package:

Thermal Resistance-Junction to Case, θ_{JC}	25°C/W
Thermal Resistance-Junction to Ambient, θ_{JA}	70°C/W

N Package:

Thermal Resistance-Junction to Case, θ_{JC}	30°C/W
Thermal Resistance-Junction to Ambient, θ_{JA}	60°C/W

L Package:

Thermal Resistance-Junction to Case, θ_{JC}	35°C/W
Thermal Resistance-Junction to Ambient, θ_{JA}	120°C/W

DW Package:

Thermal Resistance-Junction to Ambient, θ_{JA}	90°C/W
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Continuous Collector Current, I_C (SG2800, 2820)	500mA
(SG2810)	600mA
Operating Junction Temperature Hermetic (J, L Packages)	150°C
Plastic (N, DW Package)	150°C
Storage Temperature Range	-65°C to 150°C
Lead Temperature (Soldering 10 sec.)	300°C
RoHS Peak Package Solder Reflow Temp. (40 sec. max. exp.).....	260°C (+0, -5)

Note A. Junction Temperature Calculation: $T_J = T_A + (P_D \times \theta_{JA})$.

Note B. The above numbers for θ_{JC} are maximums for the limiting thermal resistance of the package in a standard mounting configuration. The θ_{JA} numbers are meant to be guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.

RECOMMENDED OPERATING CONDITIONS (Note 2)

Output Voltage, V_{CE} SG2800, SG2820 series	50V
SG2810 series	95V

Note 2. Range over which the device is functional.

Peak Collector Current, I_C SG2800, SG2820 series	350mA
SG2810 series	500mA
Operating Ambient Temperature Range	-55°C to 125°C

SELECTION GUIDE

Device	V_{CE} Max	I_C Max	Logic Inputs
SG2801	50V	500mA	General Purpose PMOS, CMOS
SG2802	50V	500mA	14V-25V PMOS
SG2803	50V	500mA	5V TTL, CMOS
SG2804	50V	500mA	6V-15V CMOS, PMOS
SG2811	50V	600mA	General Purpose PMOS, CMOS
SG2812	50V	600mA	14V-25V PMOS

Device	V_{CE} Max	I_C Max	Logic Inputs
SG2813	50V	600mA	5V TTL, CMOS
SG2814	50V	600mA	6V-15V CMOS, PMOS
SG2815	50V	600mA	High Output TTL
SG2821	95V	500mA	General Purpose PMOS, CMOS
SG2823	95V	500mA	5V TTL, CMOS
SG2824	95V	500mA	6V-15V CMOS, PMOS

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, these specifications apply over the operating ambient temperatures of $-55^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$. Low duty cycle pulse testing techniques are used which maintains junction and case temperatures equal to the ambient temperature.)

SG2801 thru SG2804

Parameter	Applicable Devices	Temp.	Test Conditions	Limits			Units
				Min.	Typ.	Max.	
Output Leakage Current (I_{CEX})	All		$V_{CE} = 50\text{V}$			100	μA
	SG2802		$V_{CE} = 50\text{V}, V_{IN} = 6\text{V}$			500	μA
	SG2804		$V_{CE} = 50\text{V}, V_{IN} = 1\text{V}$			500	μA
Collector - Emitter ($V_{CE(SAT)}$)	All	$T_A = T_{MIN}$	$I_C = 350\text{mA}, I_B = 850\mu\text{A}$		1.6	1.8	V
		$T_A = T_{MIN}$	$I_C = 200\text{mA}, I_B = 550\mu\text{A}$		1.3	1.5	V
		$T_A = T_{MIN}$	$I_C = 100\text{mA}, I_B = 350\mu\text{A}$		1.1	1.3	V
		$T_A = 25^{\circ}\text{C}$	$I_C = 350\text{mA}, I_B = 500\mu\text{A}$		1.25	1.6	V
		$T_A = 25^{\circ}\text{C}$	$I_C = 200\text{mA}, I_B = 350\mu\text{A}$		1.1	1.3	V
		$T_A = 25^{\circ}\text{C}$	$I_C = 100\text{mA}, I_B = 250\mu\text{A}$		0.9	1.1	V
		$T_A = T_{MAX}$	$I_C = 350\text{mA}, I_B = 500\mu\text{A}$		1.6	1.8	V
		$T_A = T_{MAX}$	$I_C = 200\text{mA}, I_B = 350\mu\text{A}$		1.3	1.5	V
		$T_A = T_{MAX}$	$I_C = 100\text{mA}, I_B = 250\mu\text{A}$		1.1	1.3	V
Input Current ($I_{IN(ON)}$)	SG2802		$V_{IN} = 17\text{V}$	480	850	1300	μA
	SG2803		$V_{IN} = 3.85\text{V}$	650	930	1350	μA
	SG2804		$V_{IN} = 5\text{V}$	240	350	500	μA
			$V_{IN} = 12\text{V}$	650	1000	1450	μA
Input Voltage ($V_{IN(OFF)}$) ($I_{IN(OFF)}$)	All	$T_A = T_{MAX}$	$I_C = 500\mu\text{A}$	25	50		μA
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 300\text{mA}$			18	V
	SG2802	$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 300\text{mA}$			13	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 200\text{mA}$			3.3	V
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 250\text{mA}$			3.6	V
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 300\text{mA}$			3.9	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 200\text{mA}$			2.4	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 250\text{mA}$			2.7	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 300\text{mA}$			3.0	V
	SG2804	$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 125\text{mA}$			6.0	V
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 200\text{mA}$			8.0	V
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 275\text{mA}$			10	V
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 350\text{mA}$			12	V
		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 125\text{mA}$			5.0	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 200\text{mA}$			6.0	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 275\text{mA}$			7.0	V
		$T_A = T_{MAX}$	$V_{CE} = 2\text{V}, I_C = 350\text{mA}$			8.0	V
SG2801		$T_A = T_{MIN}$	$V_{CE} = 2\text{V}, I_C = 350\text{mA}$		500		
		$T_A = 25^{\circ}\text{C}$	$V_{CE} = 2\text{V}, I_C = 350\text{mA}$		1000		
Input Capacitance (C_{IN}) (Note 3)	All	$T_A = 25^{\circ}\text{C}$			15	pF	
Turn-On Delay (TPLH)	All	$T_A = 25^{\circ}\text{C}$	$0.5 E_{IN}$ to $0.5 E_{OUT}$	250	1000	ns	
Turn-Off Delay (TPHL)	All	$T_A = 25^{\circ}\text{C}$	$0.5 E_{IN}$ to $0.5 E_{OUT}$	250	1000	ns	
Clamp Diode Leakage Current (I_R)	All		$V_R = 50\text{V}$			50	μA
Clamp Diode Forward Voltage (V_F)	All		$I_F = 350\text{mA}$			1.7	V

Note 3. These parameters, although guaranteed, are not tested in production.

ELECTRICAL CHARACTERISTICS (continued)

SG2811 thru SG2815

Parameter	Applicable Devices	Temp.	Test Conditions	Limits			Units		
				Min.	Typ.	Max.			
Output Leakage Current (I_{CEX})	All		$V_{CE} = 50V$			100	μA		
	SG2812		$V_{CE} = 50V, V_{IN} = 6V$			500	μA		
	SG2814		$V_{CE} = 50V, V_{IN} = 1V$			500	μA		
Collector - Emitter ($V_{CE(SAT)}$)	All	$T_A = T_{MIN}$	$I_C = 500mA, I_B = 1100\mu A$		1.8	2.1	V		
		$T_A = T_{MIN}$	$I_C = 350mA, I_B = 850\mu A$		1.6	1.8	V		
		$T_A = T_{MIN}$	$I_C = 200mA, I_B = 550\mu A$		1.3	1.5	V		
		$T_A = 25^\circ C$	$I_C = 500mA, I_B = 600\mu A$		1.7	1.9	V		
		$T_A = 25^\circ C$	$I_C = 350mA, I_B = 500\mu A$		1.25	1.6	V		
		$T_A = 25^\circ C$	$I_C = 200mA, I_B = 350\mu A$		1.1	1.3	V		
		$T_A = T_{MAX}$	$I_C = 500mA, I_B = 600\mu A$		1.8	2.1	V		
		$T_A = T_{MAX}$	$I_C = 350mA, I_B = 500\mu A$		1.6	1.8	V		
		$T_A = T_{MAX}$	$I_C = 200mA, I_B = 350\mu A$		1.3	1.5	V		
Input Current ($I_{IN(ON)}$)	SG2812		$V_{IN} = 17V$	480	850	1300	μA		
	SG2813		$V_{IN} = 3.85V$	650	930	1350	μA		
	SG2814		$V_{IN} = 5V$	240	350	500	μA		
	SG2815		$V_{IN} = 12V$	650	1000	1450	μA		
			$V_{IN} = 3V$	1180	1500	2400	μA		
Input Voltage ($V_{IN(OFF)}$) ($I_{IN(OFF)}$)	All	$T_A = T_{MAX}$	$I_C = 500\mu A$	25	50		μA		
	SG2812	$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 500mA$				23.5	V	
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 500mA$				17	V	
		SG2813	$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 250mA$				3.6	V
			$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 300mA$				3.9	V
			$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 500mA$				6.0	V
		SG2814	$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 250mA$				2.7	V
	$T_A = T_{MAX}$		$V_{CE} = 2V, I_C = 300mA$				3.0	V	
	$T_A = T_{MAX}$		$V_{CE} = 2V, I_C = 500mA$				3.5	V	
	SG2815		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 275mA$				10	V
			$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 350mA$				12	V
			$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 500mA$				17	V
	SG2815	$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 275mA$				7.0	V	
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 350mA$				8.0	V	
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 500mA$				9.5	V	
		SG2811	$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 350mA$				3.0	V
			$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 500mA$				3.5	V
			$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 350mA$				2.4	V
	D-C Forward Current Transfer Ratio (h_{FE})	SG2811	$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 500mA$	450				
			$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 500mA$	900				
	Input Capacitance (C_{IN}) (Note 3)	All	$T_A = 25^\circ C$	$V_{CE} = 2V, I_C = 500mA$		15	25	pF	
Turn-On Delay (TPLH)	All	$T_A = 25^\circ C$	$0.5 E_{IN}$ to $0.5 E_{OUT}$		250	1000	ns		
Turn-Off Delay (TPHL)	All	$T_A = 25^\circ C$	$0.5 E_{IN}$ to $0.5 E_{OUT}$		250	1000	ns		
Clamp Diode Leakage Current (I_R)	All		$V_R = 50V$			50	μA		
Clamp Diode Forward Voltage (V_F)	All		$I_F = 350mA$		1.7	2.0	V		
			$I_F = 500mA$			2.5	V		

Note 3. These parameters, although guaranteed, are not tested in production.

ELECTRICAL CHARACTERISTICS (continued)

SG2821 thru SG2824

Parameter	Applicable Devices	Temp.	Test Conditions	Limits			Units
				Min.	Typ.	Max.	
Output Leakage Current (I_{CEX})	All		$V_{CE} = 95V$			100	μA
	SG2824		$V_{CE} = 95V, V_{IN} = 1V$			500	μA
Collector - Emitter ($V_{CE(SAT)}$)	All	$T_A = T_{MIN}$	$I_C = 350mA, I_B = 850\mu A$		1.6	1.8	V
		$T_A = T_{MIN}$	$I_C = 200mA, I_B = 550\mu A$		1.3	1.5	V
		$T_A = T_{MIN}$	$I_C = 100mA, I_B = 350\mu A$		1.1	1.3	V
		$T_A = 25^\circ C$	$I_C = 350mA, I_B = 500\mu A$		1.25	1.6	V
		$T_A = 25^\circ C$	$I_C = 200mA, I_B = 350\mu A$		1.1	1.3	V
		$T_A = 25^\circ C$	$I_C = 100mA, I_B = 250\mu A$		0.9	1.1	V
		$T_A = T_{MAX}$	$I_C = 350mA, I_B = 500\mu A$		1.6	1.8	V
		$T_A = T_{MAX}$	$I_C = 200mA, I_B = 350\mu A$		1.3	1.5	V
		$T_A = T_{MAX}$	$I_C = 100mA, I_B = 250\mu A$		1.1	1.3	V
		Input Current ($I_{IN(ON)}$)	SG2823		$V_{IN} = 3.85V$	650	930
SG2824			$V_{IN} = 5V$	240	350	500	μA
			$V_{IN} = 12V$	650	1000	1450	μA
$I_{IN(OFF)}$	All	$T_A = T_{MAX}$	$I_C = 500\mu A$	25	50		μA
Input Voltage ($V_{IN(ON)}$)	SG2823	$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 300mA$			13	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 200mA$			3.3	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 250mA$			3.6	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 300mA$			3.9	V
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 200mA$			2.4	V
	SG2824	$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 250mA$			2.7	V
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 300mA$			3.0	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 125mA$			6.0	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 200mA$			8.0	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 275mA$			10	V
		$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 350mA$			12	V
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 125mA$			5.0	V
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 200mA$			6.0	V
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 275mA$			7.0	V
		$T_A = T_{MAX}$	$V_{CE} = 2V, I_C = 350mA$			8.0	V
D-C Forward Current	SG2821	$T_A = T_{MIN}$	$V_{CE} = 2V, I_C = 350mA$	500			
Transfer Ratio (h_{FE})		$T_A = 25^\circ C$	$V_{CE} = 2V, I_C = 350mA$	1000			
Input Capacitance (C_{IN}) (Note 3)	All	$T_A = 25^\circ C$			15	25	pF
Turn-On Delay (TPLH)	All	$T_A = 25^\circ C$	$0.5 E_{IN}$ to $0.5 E_{OUT}$		250	1000	ns
Turn-Off Delay (TPHL)	All	$T_A = 25^\circ C$	$0.5 E_{IN}$ to $0.5 E_{OUT}$		250	1000	ns
Clamp Diode Leakage Current (I_R)	All		$V_R = 95V$			50	μA
Clamp Diode Forward Voltage (V_F)	All		$I_F = 350mA$		1.7	2.0	V

Note 3. These parameters, although guaranteed, are not tested in production.

CHARACTERISTIC CURVES

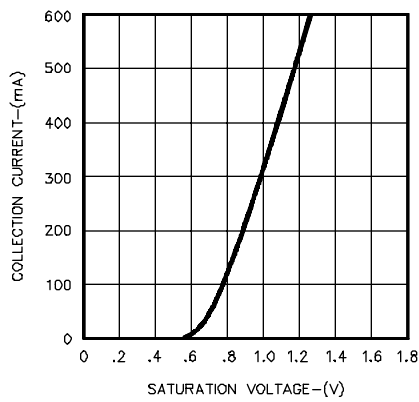


FIGURE 1.
OUTPUT CHARACTERISTICS

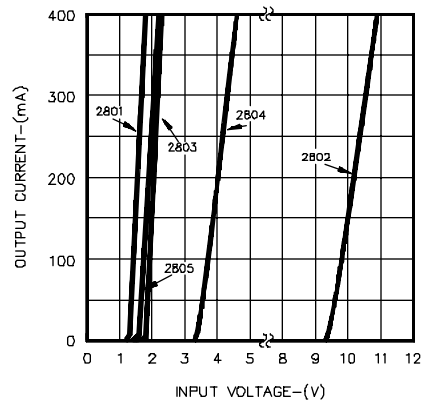


FIGURE 2.
OUTPUT CURRENT VS. INPUT VOLTAGE

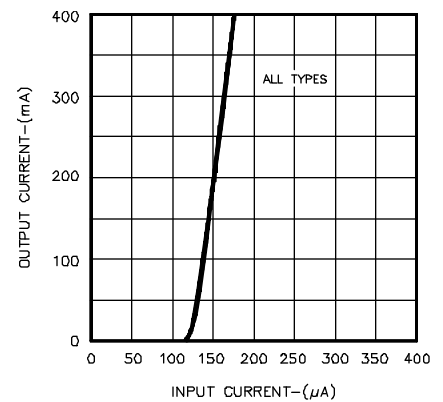


FIGURE 3.
OUTPUT CURRENT VS. INPUT CURRENT

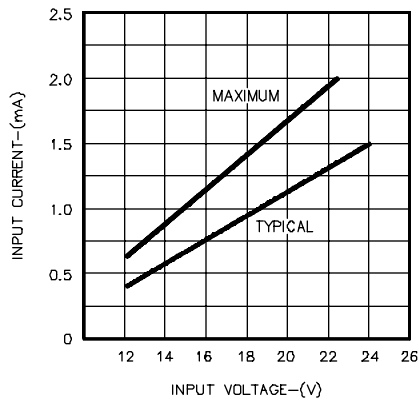


FIGURE 4.
INPUT CHARACTERISTICS - SG2802

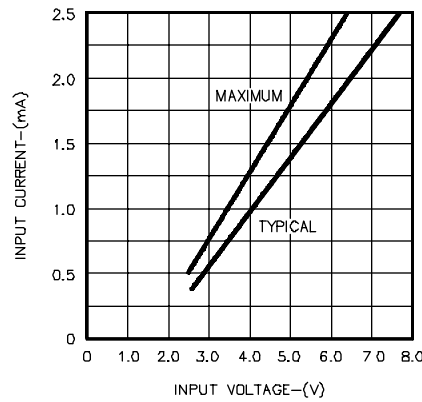


FIGURE 5.
INPUT CHARACTERISTICS - SG2803

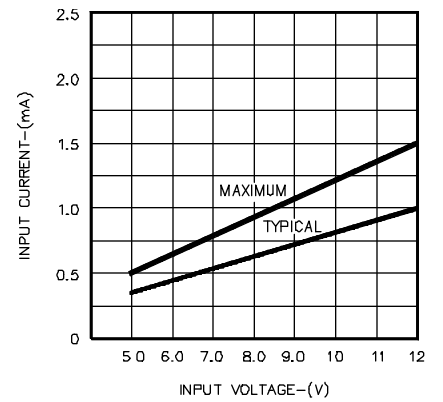


FIGURE 6.
INPUT CHARACTERISTICS - SG2804

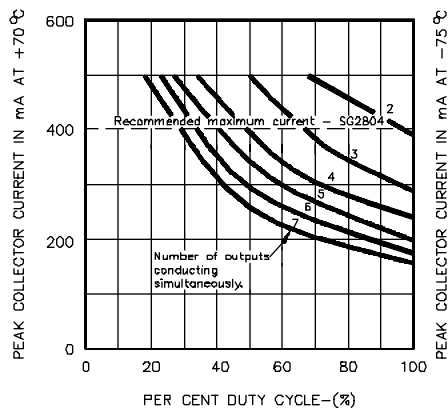
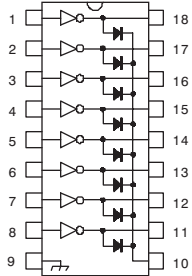
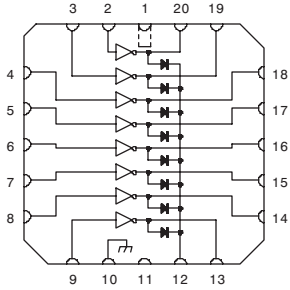


FIGURE 7.
PEAK COLLECTOR CURRENT VS. DUTY CYCLE

CONNECTION DIAGRAMS & ORDERING INFORMATION (See Notes Below)

Package	Part No. (Note 3)	Ambient Temperature Range	Connection Diagram
18-PIN CERAMIC DIP J - PACKAGE	SG28XXJ/883B JAN2801J JAN2802J JAN2803J JAN2804J SG2803J/DESC SG2821J/DESC SG2823J/DESC SG2824J/DESC SG28XXJ	-55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C	
18-PIN PLASTIC DIP N - PACKAGE	SG2803N SG2823N	0°C to 70°C 0°C to 70°C	N Package: RoHS Compliant / Pb-free Transition DC: 0503 N Package: RoHS / Pb-free 100% Matte Tin Lead Finish
18-PIN PLASTIC DIP DW - PACKAGE	SG2803DW SG2823DW	0°C to 70°C 0°C to 70°C	DW Package: RoHS Compliant / Pb-free Transition DC: 0516 DW Package: RoHS / Pb-free 100% Matte Tin Lead Finish
20-PIN CERAMIC LEADLESS CHIP CARRIER L- PACKAGE	SG28XXL/883B SG2803L/DESC SG2821L/DESC SG2823L/DESC SG2824L/DESC SG28XXL	-55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C -55°C to 125°C	

- Note
1. Contact factory for JAN and DESC product availability.
 2. All parts are viewed from the top.
 3. See Selection Guide for specific device types.